

# Linear Voltage Tracking Regulator - Micropower Low Dropout, Line Driver

200 mA

## CS8182

The CS8182 is a monolithic integrated low dropout tracking regulator designed to provide an adjustable buffered output voltage that closely tracks ( $\pm 10$  mV) the reference input. The output delivers up to 200 mA while being able to be configured higher, lower or equal to the reference voltages.

The device has been designed to operate over a wide range (2.8 V to 45 V) while still maintaining excellent DC characteristics. The CS8182 is protected from reverse battery, short circuit and thermal runaway conditions. The device also can withstand 45 V load dump transients and -50 V reverse polarity input voltage transients. This makes it suitable for use in automotive environments.

The  $V_{REF}/ENABLE$  lead serves two purposes. It is used to provide the input voltage as a reference for the output and it also can be pulled low to place the device in sleep mode where it nominally draws 30  $\mu$ A from the supply.

### Features

- 200 mA Source Capability
- Output Tracks within  $\pm 10$  mV Worst Case
- Low Dropout (0.35 V Typ. @ 200 mA)
- Low Quiescent Current
- Thermal Shutdown
- Short Circuit Protection
- Wide Operating Range
- Internally Fused Leads in SO-8 Package
- For Automotive and Other Applications Requiring Site and Change Control
- These are Pb-Free Devices

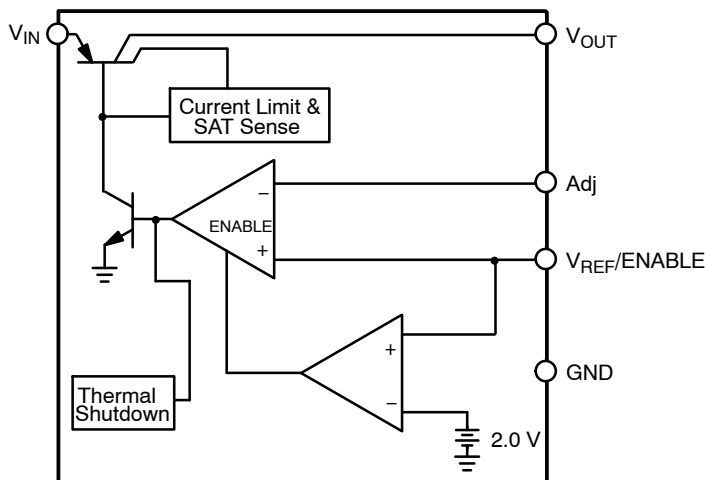
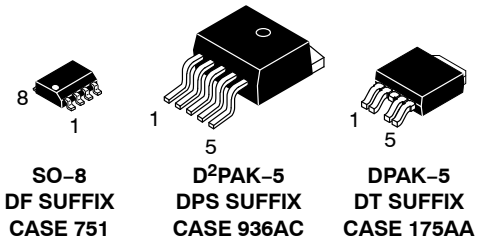
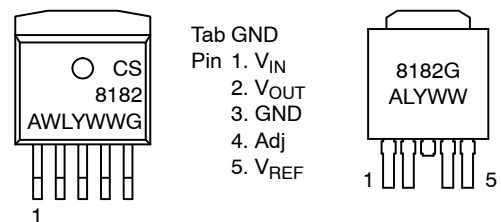
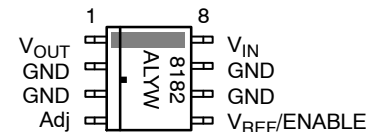


Figure 1. Block Diagram



### PIN CONNECTIONS AND MARKING DIAGRAMS



- A = Assembly Location
- WL, L = Wafer Lot
- Y = Year
- WW, W = Work Week
- G or ■ = Pb-Free Device

### ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 9 of this data sheet.

NOTE: Some of the devices on this data sheet have been **DISCONTINUED**. Please refer to the table on page 9.

## PACKAGE PIN DESCRIPTION

| Package Lead Number |                          |            | Lead Symbol              | Function                           |
|---------------------|--------------------------|------------|--------------------------|------------------------------------|
| SO-8                | D <sup>2</sup> PAK 5-PIN | DPAK 5-PIN |                          |                                    |
| 8                   | 1                        | 1          | V <sub>IN</sub>          | Input Voltage                      |
| 1                   | 2                        | 2          | V <sub>OUT</sub>         | Regulated Output                   |
| 2, 3, 6, 7          | 3                        | 3          | GND                      | Ground                             |
| 4                   | 4                        | 4          | Adj                      | Adjust Lead                        |
| 5                   | 5                        | 5          | V <sub>REF</sub> /ENABLE | Reference Voltage and ENABLE Input |

## MAXIMUM RATINGS

| Rating  | Value                   | Unit |
|---|-------------------------|------|
| Storage Temperature Range   | -65 to +150             | °C   |
| Junction Temperature  | +150                    | °C   |
| Supply Voltage Range (Continuous)   | -16 to 45               | V    |
| Peak Transient Voltage (V <sub>IN</sub> = 14 V, Load Dump Transient = 31 V)   | 45                      | V    |
| Voltage Range (Adj, V <sub>OUT</sub> , V <sub>REF</sub> /ENABLE)  | -10 to +V <sub>IN</sub> | V    |
| Package Thermal Resistance, SO-8:<br>Junction-to-Case, R <sub>θJC</sub><br>Junction-to-Air, R <sub>θJA</sub>              | 25                      | °C/W |
|   | 80                      | °C/W |
| Package Thermal Resistance, D <sup>2</sup> PAK<br>Junction-to-Case, R <sub>θJC</sub><br>Junction-to-Air, R <sub>θJA</sub> | 4.0                     | °C/W |
|   | 48                      | °C/W |
| Package Thermal Resistance, DPAK<br>Junction-to-Case, R <sub>θJC</sub><br>Junction-to-Air, R <sub>θJA</sub>               | 8.0                     | °C/W |
|   | 64                      | °C/W |
| ESD Capability (Human Body Model)<br>(Machine Model)  | 2.0                     | kV   |
|   | 200                     | V    |
| Lead Temperature Soldering: (Note 1)  | (SO-8)                  | 240  |
|   | (D <sup>2</sup> PAK)    | 225  |
|   | (DPAK)                  | 260  |
|   |                         | °C   |

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. 60 second maximum above 183°C.

## RECOMMENDED OPERATING RANGES

| Rating                                    | Value       | Unit |
|---|-------------|------|
| Junction Temperature, T <sub>J</sub>      | -40 to +125 | °C   |
| Input Voltage, Continuous V <sub>IN</sub> | 3.4 to 45   | V    |

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

## CS8182

**ELECTRICAL CHARACTERISTICS** ( $V_{IN} = 14\text{ V}$ ;  $V_{REF}/ENABLE > 2.75\text{ V}$ ;  $-40^{\circ}\text{C} < T_J < +125^{\circ}\text{C}$ ;  $C_{OUT} \geq 10\text{ }\mu\text{F}$ ;  $0.1\text{ }\Omega < C_{OUT-ESR} < 1.0\text{ }\Omega$  @  $10\text{ kHz}$ , unless otherwise specified.)

| Parameter                                       | Test Conditions  | Min  | Typ | Max | Unit               |
|---|--|------|-----|-----|--------------------|
| <b>Regular Output</b>                           |  |      |     |     |                    |
| $V_{REF} - V_{OUT}$<br>$V_{OUT}$ Tracking Error | $4.5\text{ V} \leq V_{IN} \leq 26\text{ V}$ , $100\text{ }\mu\text{A} \leq I_{OUT} \leq 200\text{ mA}$ , Note 2<br>$V_{IN} = 12\text{ V}$ , $I_{OUT} = 30\text{ mA}$ , $V_{REF} = 5.0\text{ V}$ , Note 2 | -10  | -   | 10  | mV                 |
|   |  | -5.0 | -   | 5   | mV                 |
| Dropout Voltage ( $V_{IN} - V_{OUT}$ )          | $I_{OUT} = 100\text{ }\mu\text{A}$<br>$I_{OUT} = 30\text{ mA}$<br>$I_{OUT} = 200\text{ mA}$  | -    | 100 | 150 | mV                 |
|   |  | -    | -   | 500 | mV                 |
|   |  | -    | 350 | 600 | mV                 |
| Line Regulation                                 | $4.5\text{ V} \leq V_{IN} \leq 26\text{ V}$ , Note 2   | -    | -   | 10  | mV                 |
| Load Regulation                                 | $100\text{ }\mu\text{A} \leq I_{OUT} \leq 200\text{ mA}$ , Note 2  | -    | -   | 10  | mV                 |
| Adj Lead Current                                | Loop in Regulation   | -    | 0.2 | 1.0 | $\mu\text{A}$      |
| Current Limit                                   | $V_{IN} = 14\text{ V}$ , $V_{REF} = 5.0\text{ V}$ , $V_{OUT} = 90\%$ of $V_{REF}$ , Note 2   | 250  | -   | 700 | mA                 |
| Quiescent Current ( $I_{IN} - I_{OUT}$ )        | $V_{IN} = 12\text{ V}$ , $I_{OUT} = 200\text{ mA}$<br>$V_{IN} = 12\text{ V}$ , $I_{OUT} = 100\text{ }\mu\text{A}$<br>$V_{IN} = 12\text{ V}$ , $V_{REF}/ENABLE = 0\text{ V}$                              | -    | 15  | 25  | mA                 |
|   |  | -    | 75  | 150 | $\mu\text{A}$      |
|   |  | -    | 30  | 55  | $\mu\text{A}$      |
| Reverse Current                                 | $V_{OUT} = 5.0\text{ V}$ , $V_{IN} = 0\text{ V}$   | -    | 0.2 | 1.5 | mA                 |
| Ripple Rejection                                | $f = 120\text{ Hz}$ , $I_{OUT} = 200\text{ mA}$ , $4.5\text{ V} \leq V_{IN} \leq 26\text{ V}$  | 60   | -   | -   | dB                 |
| Thermal Shutdown                                | GBD  | 150  | 180 | 210 | $^{\circ}\text{C}$ |

### $V_{REF}/ENABLE$

|                    |                  |      |      |      |               |
|--------------------|------------------|------|------|------|---------------|
| Enable Voltage     | -                | 0.80 | 2.00 | 2.75 | V             |
| Input Bias Current | $V_{REF}/ENABLE$ | -    | 0.2  | 1.0  | $\mu\text{A}$ |

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

2.  $V_{OUT}$  connected to Adj lead.

## TYPICAL CHARACTERISTICS

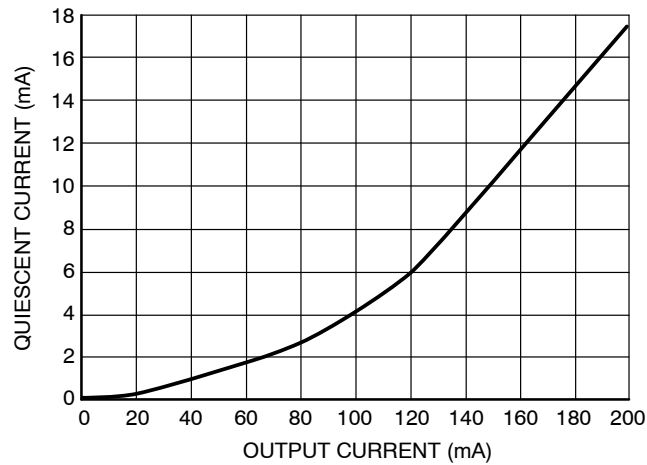


Figure 2. Quiescent Current vs. Output Current

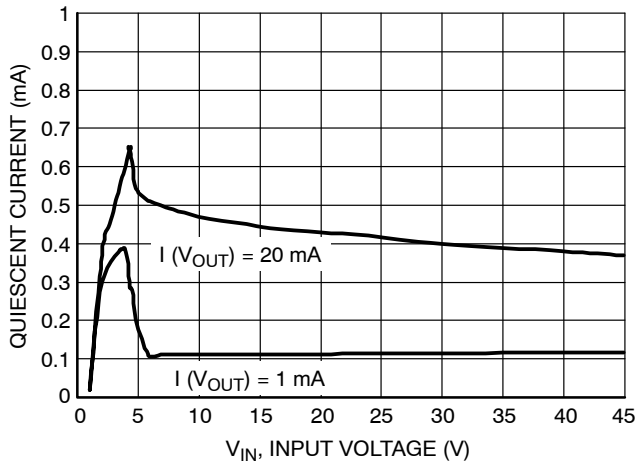


Figure 3. Quiescent Current vs. Input Voltage (Operating Mode)

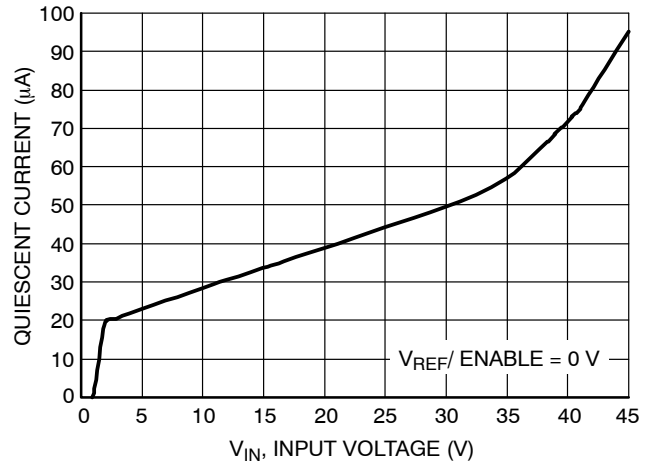
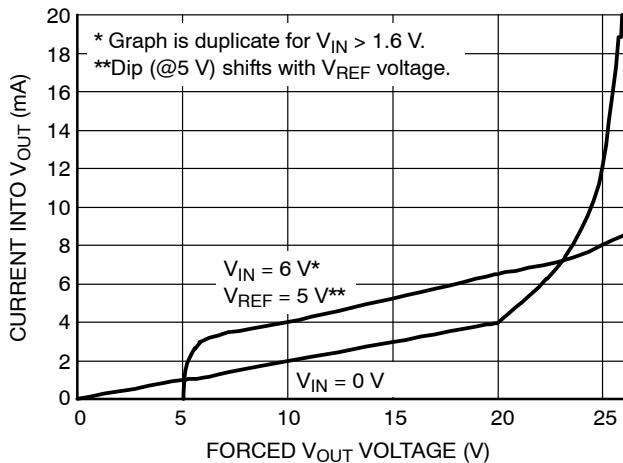
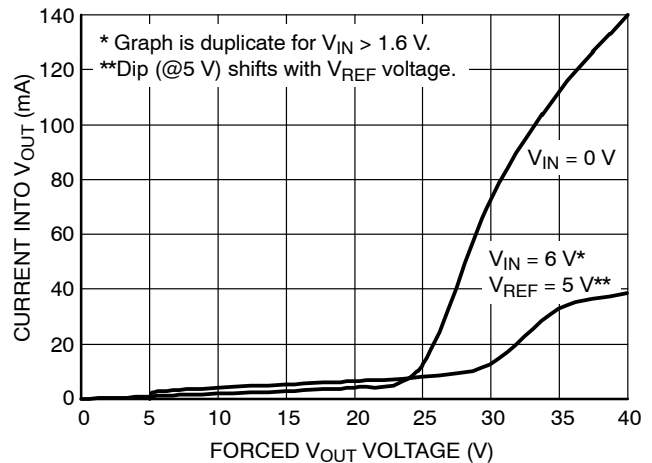


Figure 4. Quiescent Current vs. Input Voltage (Sleep Mode)

Figure 5.  $V_{OUT}$  Reverse CurrentFigure 6.  $V_{OUT}$  Reverse Current

## CIRCUIT DESCRIPTION

### ENABLE Function

By pulling the  $V_{REF}/ENABLE$  lead below 2.0 V typically, (see Figure 10 or Figure 11), the IC is disabled and enters a sleep state where the device draws less than 55  $\mu A$  from supply. When the  $V_{REF}/ENABLE$  lead is greater than 2.75 V,  $V_{OUT}$  tracks the  $V_{REF}/ENABLE$  lead normally.

### Output Voltage

The output is capable of supplying 200 mA to the load while configured as a similar (Figure 7), lower (Figure 9), or higher (Figure 8) voltage as the reference lead. The Adj lead acts as the inverting terminal of the op amp and the  $V_{REF}$  lead as the non-inverting.

The device can also be configured as a high-side driver as displayed in Figure 12.

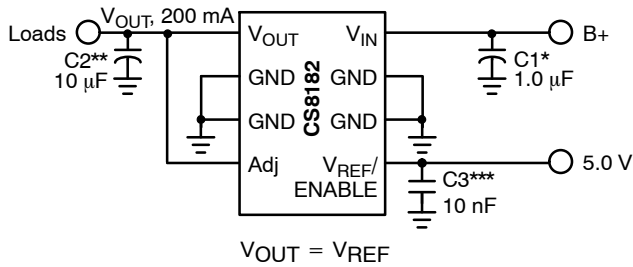


Figure 7. Tracking Regulator at the Same Voltage

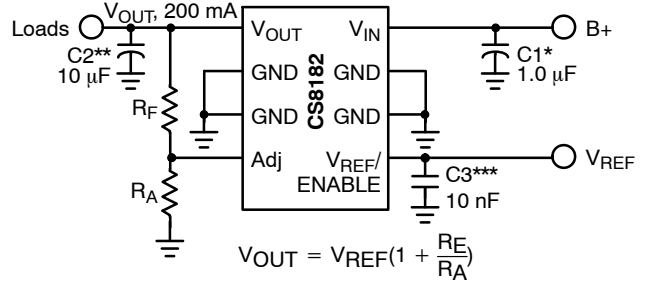


Figure 8. Tracking Regulator at Higher Voltages

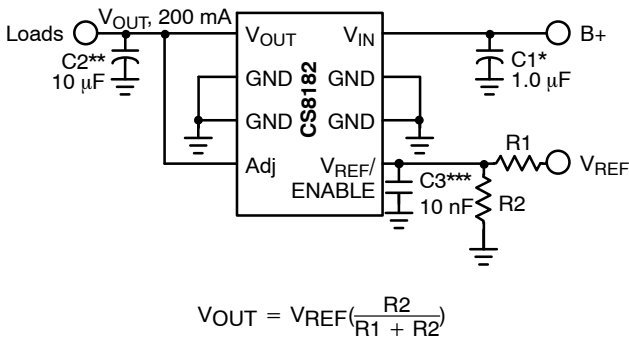


Figure 9. Tracking Regulator at Lower Voltages

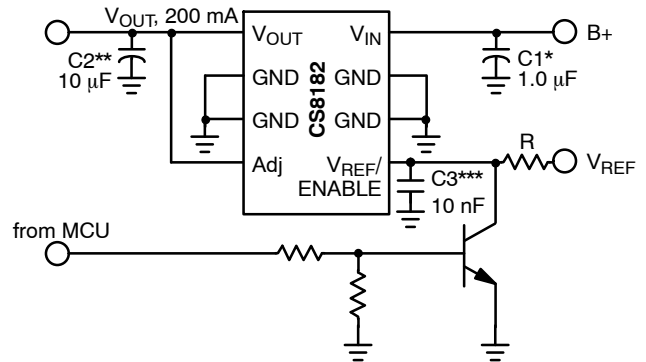


Figure 10. Tracking Regulator with ENABLE Circuit

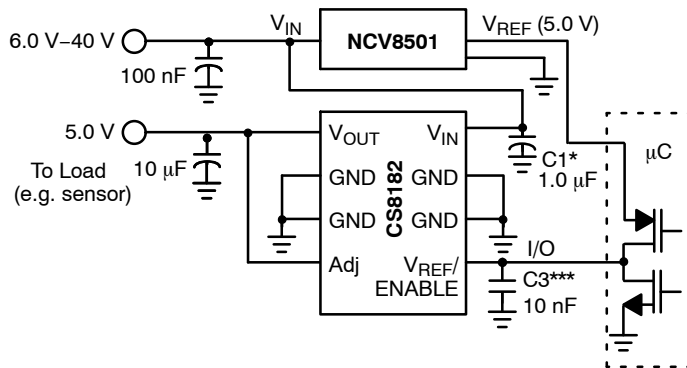


Figure 11. Alternative ENABLE Circuit

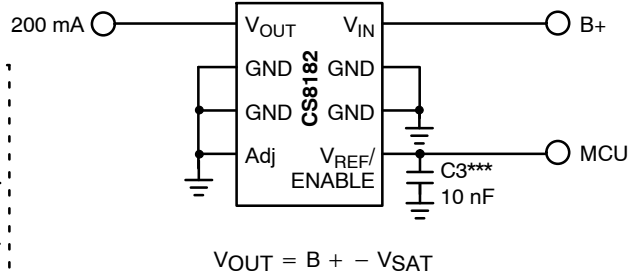


Figure 12. High-Side Driver

- \* C1 is required if the regulator is far from the power source filter.
- \*\* C2 is required for stability.
- \*\*\* C3 is recommended for EMC susceptibility.

## APPLICATION NOTES

### V<sub>OUT</sub> Short to Battery

The CS8182 will survive a short to battery when hooked up the conventional way as shown in Figure 13. No damage to the part will occur. The part also endures a short to battery when powered by an isolated supply at a lower voltage as in

Figure 14. In this case the CS8182 supply input voltage is set at 7 V when a short to battery (14 V typical) occurs on V<sub>OUT</sub> which normally runs at 5 V. The current into the device (ammeter in Figure 14) will draw additional current as displayed in Figure 15.

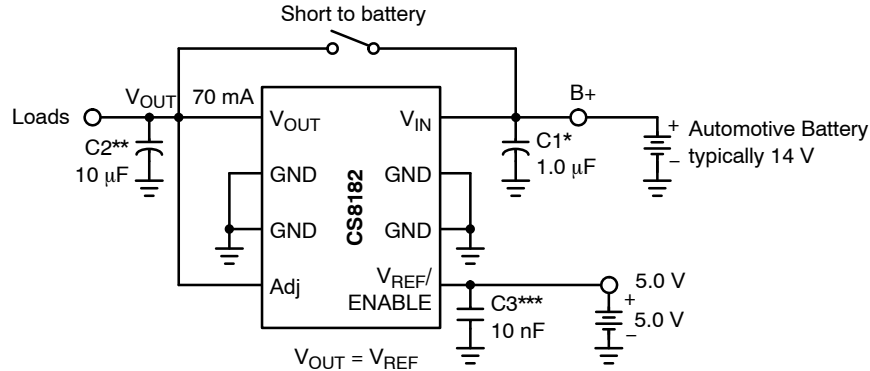
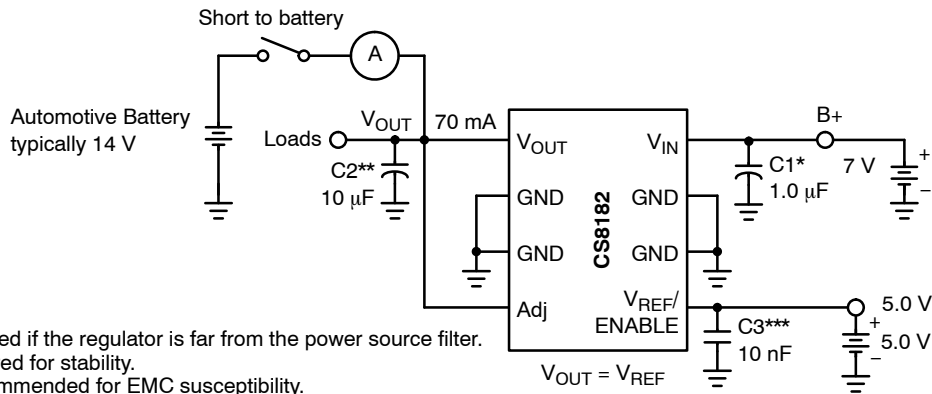


Figure 13.



\* C1 is required if the regulator is far from the power source filter.  
 \*\* C2 is required for stability.  
 \*\*\* C3 is recommended for EMC susceptibility.

Figure 14.

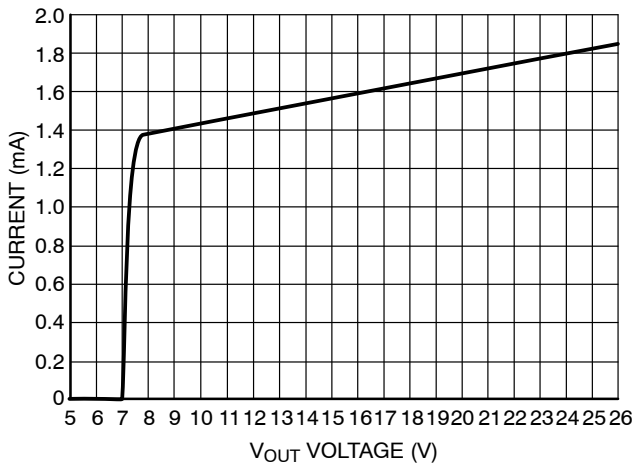


Figure 15. V<sub>OUT</sub> Short to Battery

### Switched Application

The CS8182 has been designed for use in systems where the reference voltage on the V<sub>REF/ENABLE</sub> pin is continuously on. Typically, the current into the V<sub>REF/ENABLE</sub> pin will be less than 1.0 μA when the voltage on the V<sub>IN</sub> pin (usually the ignition line) has been switched out (V<sub>IN</sub> can be at high impedance or at ground.) Reference Figure 16.

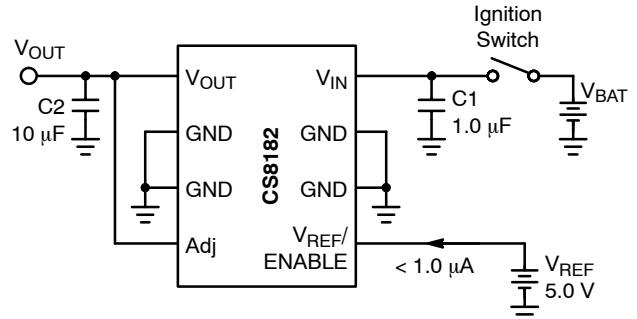


Figure 16.

### External Capacitors

The output capacitor for the CS8182 is required for stability. Without it, the regulator output will oscillate. Actual size and type may vary depending upon the application load and temperature range. Capacitor effective series resistance (ESR) is also a factor in the IC stability. Worst-case is determined at the minimum ambient temperature and maximum load expected.

The output capacitor can be increased in size to any desired value above the minimum. One possible purpose of this would be to maintain the output voltage during brief conditions of negative input transients that might be characteristic of a particular system.

The capacitor must also be rated at all ambient temperatures expected in the system. To maintain regulator stability down to  $-40^{\circ}\text{C}$ , a capacitor rated at that temperature must be used.

### Ceramic Capacitor Stability

The CS8182 has been verified to work with ceramic output capacitors with an additional series resistor simulating traditional ESR of tantalum capacitors; however, it has been determined the best operational performance is with a  $330\text{ m}\Omega$  series resistor (or parallel combination of three  $1\text{ }\Omega$  resistors) in conjunction with a  $22\text{ }\mu\text{F}$  output capacitor. Values outside of this are known to have limited performance with respect to stability. For more information, please contact your local **onsemi** sales office.

### Calculating Power Dissipation in a Single Output Linear Regulator

The maximum power dissipation for a single output regulator (Figure 17) is:

$$\text{PD}(\text{max}) = \{V_{\text{IN}}(\text{max}) - V_{\text{OUT}}(\text{min})\} I_{\text{OUT}}(\text{max}) + V_{\text{IN}}(\text{max}) I_{\text{Q}} \quad (1)$$

where:

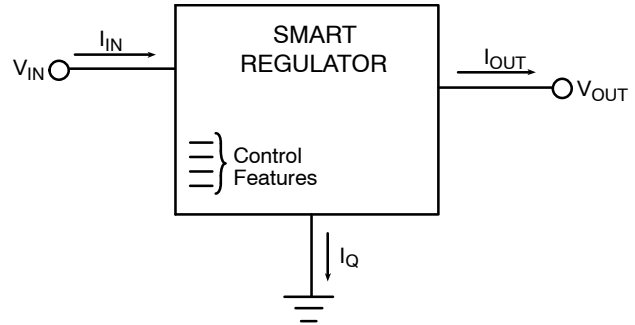
$V_{\text{IN}}(\text{max})$  is the maximum input voltage,  
 $V_{\text{OUT}}(\text{min})$  is the minimum output voltage,  
 $I_{\text{OUT}}(\text{max})$  is the maximum output current, for the application, and  
 $I_{\text{Q}}$  is the quiescent current the regulator consumes at  $I_{\text{OUT}}(\text{max})$ .

Once the value of  $\text{PD}(\text{max})$  is known, the maximum permissible value of  $R_{\theta\text{JA}}$  can be calculated:

$$R_{\theta\text{JA}} = \frac{150^{\circ}\text{C} - T_{\text{A}}}{\text{PD}} \quad (2)$$

The value of  $R_{\theta\text{JA}}$  can then be compared with those in the package section of the data sheet. Those packages with  $R_{\theta\text{JA}}$ 's less than the calculated value in equation 2 will keep the die temperature below  $150^{\circ}\text{C}$ .

In some cases, none of the packages will be sufficient to dissipate the heat generated by the IC, and an external heat sink will be required.



**Figure 17. Single Output Regulator with Key Performance Parameters Labeled**

### Heatsinks

A heatsink effectively increases the surface area of the package to improve the flow of heat away from the IC and into the surrounding air.

Each material in the heat flow path between the IC and the outside environment will have a thermal resistance. Like series electrical resistances, these resistances are summed to determine the value of  $R_{\theta\text{JA}}$ :

$$R_{\theta\text{JA}} = R_{\theta\text{JC}} + R_{\theta\text{CS}} + R_{\theta\text{SA}} \quad (3)$$

where:

$R_{\theta\text{JC}}$  = the junction-to-case thermal resistance,  
 $R_{\theta\text{CS}}$  = the case-to-heatsink thermal resistance, and  
 $R_{\theta\text{SA}}$  = the heatsink-to-ambient thermal resistance.

$R_{\theta\text{JC}}$  appears in the package section of the data sheet. Like  $R_{\theta\text{JA}}$ , it is a function of package type.  $R_{\theta\text{CS}}$  and  $R_{\theta\text{SA}}$  are functions of the package type, heatsink and the interface between them. These values appear in heat sink data sheets of heatsink manufacturers.

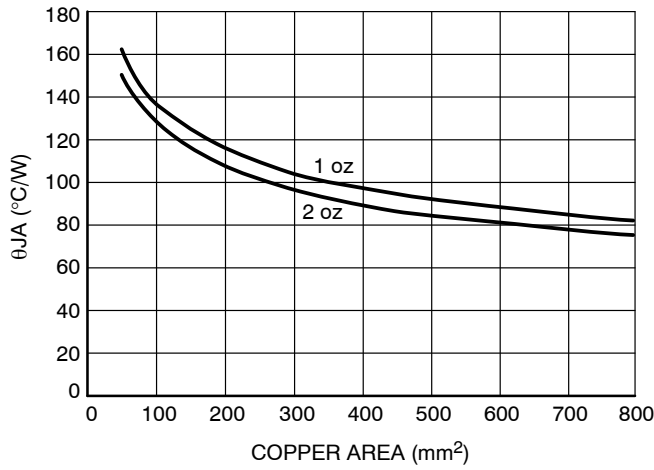


Figure 18. 8 Lead SOIC (Fused) Thermal Resistance

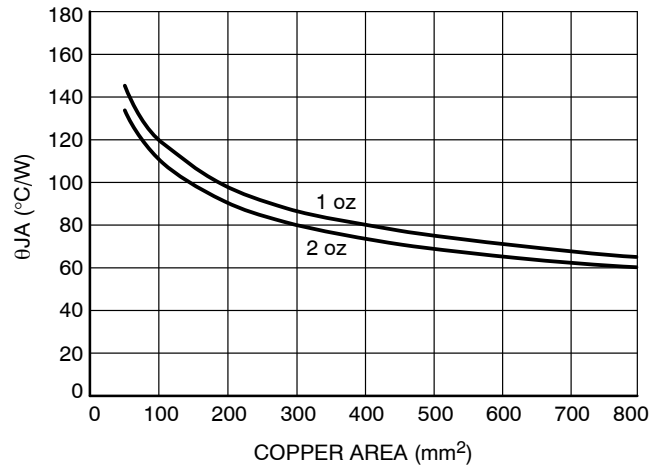


Figure 19. 5 Lead DPAK Thermal Resistance

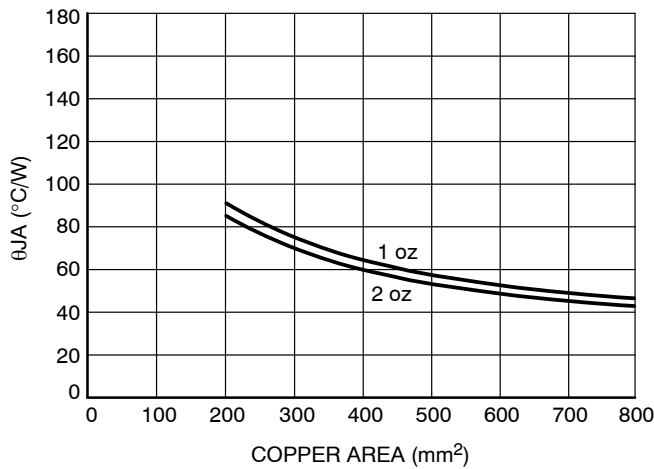


Figure 20. 5 Lead D<sup>2</sup>PAK Thermal Resistance

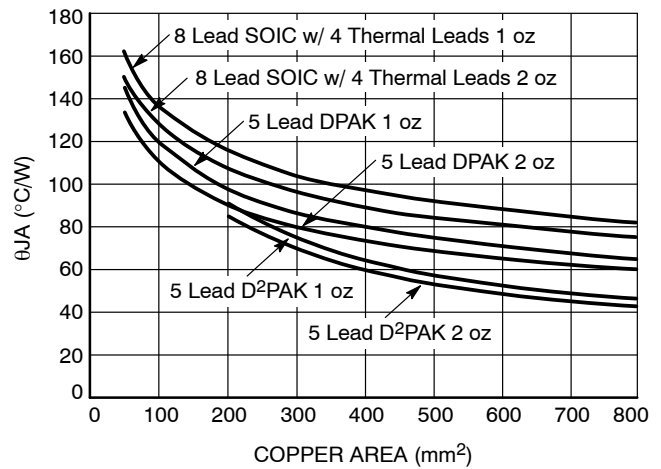


Figure 21. Thermal Resistance Summary



## CS8182

### ORDERING INFORMATION

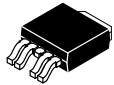
| Device       | Package           | Shipping <sup>†</sup> |
|--------------|-------------------|-----------------------|
| CS8182YDFR8G | SO-8<br>(Pb-Free) | 2500 / Tape & Reel    |

### DISCONTINUED (Note 3)

|               |                                       |                    |
|---------------|---------------------------------------|--------------------|
| CS8182YDF8G   | SO-8<br>(Pb-Free)                     | 95 Units / Rail    |
| CS8182YDPS5G  | D <sup>2</sup> PAK 5-PIN<br>(Pb-Free) | 50 Units / Rail    |
| CS8182YDPSR5G | D <sup>2</sup> PAK 5-PIN<br>(Pb-Free) | 750 / Tape & Reel  |
| CS8182DTG     | DPAK 5L<br>(Pb-Free)                  | 50 Units / Rail    |
| CS8182DTRKG   | DPAK 5L<br>(Pb-Free)                  | 2500 / Tape & Reel |

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

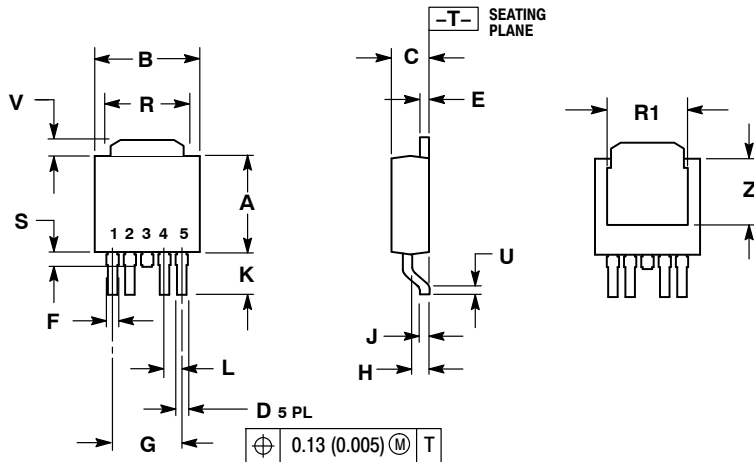
3. **DISCONTINUED:** These devices are not recommended for new design. Please contact your **onsemi** representative for information. The most current information on these devices may be available on [www.onsemi.com](http://www.onsemi.com).



SCALE 1:1

**DPAK-5, CENTER LEAD CROP**  
CASE 175AA  
ISSUE B

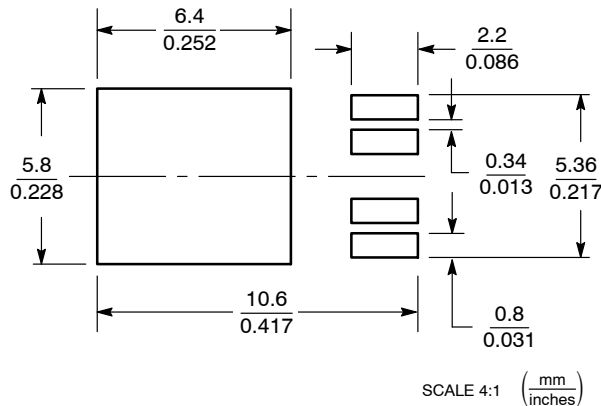
DATE 15 MAY 2014



## NOTES:

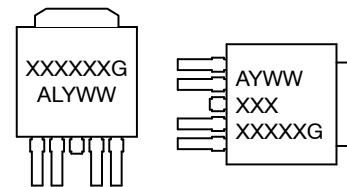
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2. CONTROLLING DIMENSION: INCH.

| DIM | INCHES    |       | MILLIMETERS |      |
|-----|-----------|-------|-------------|------|
|     | MIN       | MAX   | MIN         | MAX  |
| A   | 0.235     | 0.245 | 5.97        | 6.22 |
| B   | 0.250     | 0.265 | 6.35        | 6.73 |
| C   | 0.086     | 0.094 | 2.19        | 2.38 |
| D   | 0.020     | 0.028 | 0.51        | 0.71 |
| E   | 0.018     | 0.023 | 0.46        | 0.58 |
| F   | 0.024     | 0.032 | 0.61        | 0.81 |
| G   | 0.180 BSC |       | 4.56 BSC    |      |
| H   | 0.034     | 0.040 | 0.87        | 1.01 |
| J   | 0.018     | 0.023 | 0.46        | 0.58 |
| K   | 0.102     | 0.114 | 2.60        | 2.89 |
| L   | 0.045 BSC |       | 1.14 BSC    |      |
| R   | 0.170     | 0.190 | 4.32        | 4.83 |
| R1  | 0.185     | 0.210 | 4.70        | 5.33 |
| S   | 0.025     | 0.040 | 0.63        | 1.01 |
| U   | 0.020     | ---   | 0.51        | ---  |
| V   | 0.035     | 0.050 | 0.89        | 1.27 |
| Z   | 0.155     | 0.170 | 3.93        | 4.32 |

**RECOMMENDED  
SOLDERING FOOTPRINT\***


SCALE 4:1 (mm / inches)

\*For additional information on our Pb-Free strategy and soldering details, please download the **onsemi** Soldering and Mounting Techniques Reference Manual, [SOLDERM/D](#).

**GENERIC  
MARKING DIAGRAMS\***


IC

Discrete

XXXXXX = Device Code  
A = Assembly Location  
L = Wafer Lot  
Y = Year  
WW = Work Week  
G = Pb-Free Package

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "▪", may or may not be present.

|                         |                                |  |
|-------------------------|--------------------------------|--|
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| <b>DESCRIPTION:</b>     | <b>DPAK-5 CENTER LEAD CROP</b> | <b>PAGE 1 OF 1</b>   |

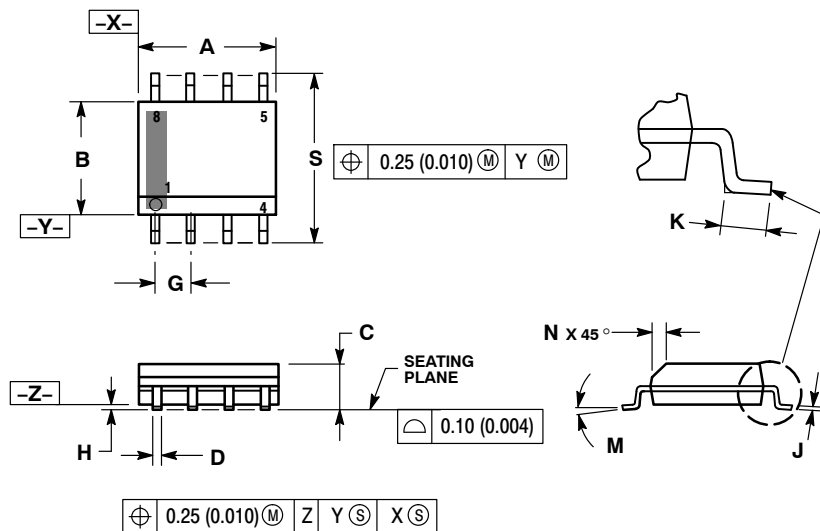
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SCALE 1:1

SOIC-8 NB  
CASE 751-07  
ISSUE AK

DATE 16 FEB 2011

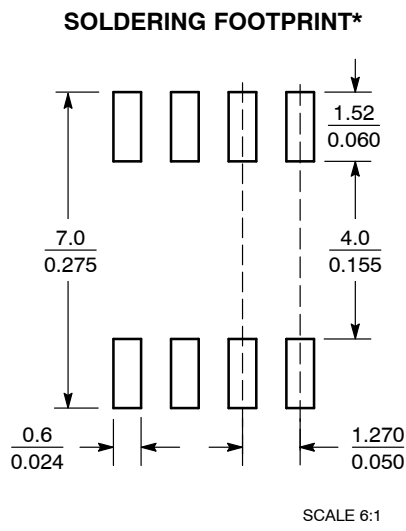


NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.
3. DIMENSION A AND B DO NOT INCLUDE MOLD PROTRUSION.
4. MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE.
5. DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127 (0.005) TOTAL IN EXCESS OF THE D DIMENSION AT MAXIMUM MATERIAL CONDITION.
6. 751-01 THRU 751-06 ARE OBSOLETE. NEW STANDARD IS 751-07.

| DIM | MILLIMETERS |      | INCHES    |       |
|-----|-------------|------|-----------|-------|
|     | MIN         | MAX  | MIN       | MAX   |
| A   | 4.80        | 5.00 | 0.189     | 0.197 |
| B   | 3.80        | 4.00 | 0.150     | 0.157 |
| C   | 1.35        | 1.75 | 0.053     | 0.069 |
| D   | 0.33        | 0.51 | 0.013     | 0.020 |
| G   | 1.27 BSC    |      | 0.050 BSC |       |
| H   | 0.10        | 0.25 | 0.004     | 0.010 |
| J   | 0.19        | 0.25 | 0.007     | 0.010 |
| K   | 0.40        | 1.27 | 0.016     | 0.050 |
| M   | 0°          | 8°   | 0°        | 8°    |
| N   | 0.25        | 0.50 | 0.010     | 0.020 |
| S   | 5.80        | 6.20 | 0.228     | 0.244 |

GENERIC  
MARKING DIAGRAM\*



XXXXXX = Specific Device Code  
A = Assembly Location  
L = Wafer Lot  
Y = Year  
W = Work Week  
▪ = Pb-Free Package

XXXXXX = Specific Device Code  
A = Assembly Location  
Y = Year  
WW = Work Week  
▪ = Pb-Free Package

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "▪", may or may not be present. Some products may not follow the Generic Marking.

\*For additional information on our Pb-Free strategy and soldering details, please download the **onsemi** Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

STYLES ON PAGE 2

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| DESCRIPTION:     | SOIC-8 NB   | PAGE 1 OF 2   |

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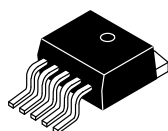
**SOIC-8 NB**  
**CASE 751-07**  
**ISSUE AK**

DATE 16 FEB 2011

|   |  |  |  |
|---|--|--|--|
| <b>STYLE 1:</b><br>PIN 1. EMITTER<br>2. COLLECTOR<br>3. COLLECTOR<br>4. EMITTER<br>5. EMITTER<br>6. BASE<br>7. BASE<br>8. EMITTER   | <b>STYLE 2:</b><br>PIN 1. COLLECTOR, DIE, #1<br>2. COLLECTOR, #1<br>3. COLLECTOR, #2<br>4. COLLECTOR, #2<br>5. BASE, #2<br>6. EMITTER, #2<br>7. BASE, #1<br>8. EMITTER, #1               | <b>STYLE 3:</b><br>PIN 1. DRAIN, DIE #1<br>2. DRAIN, #1<br>3. DRAIN, #2<br>4. DRAIN, #2<br>5. GATE, #2<br>6. SOURCE, #2<br>7. GATE, #1<br>8. SOURCE, #1                            | <b>STYLE 4:</b><br>PIN 1. ANODE<br>2. ANODE<br>3. ANODE<br>4. ANODE<br>5. ANODE<br>6. ANODE<br>7. ANODE<br>8. COMMON CATHODE   |
| <b>STYLE 5:</b><br>PIN 1. DRAIN<br>2. DRAIN<br>3. DRAIN<br>4. DRAIN<br>5. GATE<br>6. GATE<br>7. SOURCE<br>8. SOURCE   | <b>STYLE 6:</b><br>PIN 1. SOURCE<br>2. DRAIN<br>3. DRAIN<br>4. SOURCE<br>5. SOURCE<br>6. GATE<br>7. GATE<br>8. SOURCE  | <b>STYLE 7:</b><br>PIN 1. INPUT<br>2. EXTERNAL BYPASS<br>3. THIRD STAGE SOURCE<br>4. GROUND<br>5. DRAIN<br>6. GATE 3<br>7. SECOND STAGE Vd<br>8. FIRST STAGE Vd                    | <b>STYLE 8:</b><br>PIN 1. COLLECTOR, DIE #1<br>2. BASE, #1<br>3. BASE, #2<br>4. COLLECTOR, #2<br>5. COLLECTOR, #2<br>6. EMITTER, #2<br>7. EMITTER, #1<br>8. COLLECTOR, #1                              |
| <b>STYLE 9:</b><br>PIN 1. EMITTER, COMMON<br>2. COLLECTOR, DIE #1<br>3. COLLECTOR, DIE #2<br>4. EMITTER, COMMON<br>5. EMITTER, COMMON<br>6. BASE, DIE #2<br>7. BASE, DIE #1<br>8. EMITTER, COMMON | <b>STYLE 10:</b><br>PIN 1. GROUND<br>2. BIAS 1<br>3. OUTPUT<br>4. GROUND<br>5. GROUND<br>6. BIAS 2<br>7. INPUT<br>8. GROUND  | <b>STYLE 11:</b><br>PIN 1. SOURCE 1<br>2. GATE 1<br>3. SOURCE 2<br>4. GATE 2<br>5. DRAIN 2<br>6. DRAIN 2<br>7. DRAIN 1<br>8. DRAIN 1   | <b>STYLE 12:</b><br>PIN 1. SOURCE<br>2. SOURCE<br>3. SOURCE<br>4. GATE<br>5. DRAIN<br>6. DRAIN<br>7. DRAIN<br>8. DRAIN   |
| <b>STYLE 13:</b><br>PIN 1. N.C.<br>2. SOURCE<br>3. SOURCE<br>4. GATE<br>5. DRAIN<br>6. DRAIN<br>7. DRAIN<br>8. DRAIN  | <b>STYLE 14:</b><br>PIN 1. N-SOURCE<br>2. N-GATE<br>3. P-SOURCE<br>4. P-GATE<br>5. P-DRAIN<br>6. P-DRAIN<br>7. N-DRAIN<br>8. N-DRAIN   | <b>STYLE 15:</b><br>PIN 1. ANODE 1<br>2. ANODE 1<br>3. ANODE 1<br>4. ANODE 1<br>5. CATHODE, COMMON<br>6. CATHODE, COMMON<br>7. CATHODE, COMMON<br>8. CATHODE, COMMON               | <b>STYLE 16:</b><br>PIN 1. EMITTER, DIE #1<br>2. BASE, DIE #1<br>3. EMITTER, DIE #2<br>4. BASE, DIE #2<br>5. COLLECTOR, DIE #2<br>6. COLLECTOR, DIE #2<br>7. COLLECTOR, DIE #1<br>8. COLLECTOR, DIE #1 |
| <b>STYLE 17:</b><br>PIN 1. VCC<br>2. V2OUT<br>3. V1OUT<br>4. TXE<br>5. RXE<br>6. VEE<br>7. GND<br>8. ACC  | <b>STYLE 18:</b><br>PIN 1. ANODE<br>2. ANODE<br>3. SOURCE<br>4. GATE<br>5. DRAIN<br>6. DRAIN<br>7. CATHODE<br>8. CATHODE   | <b>STYLE 19:</b><br>PIN 1. SOURCE 1<br>2. GATE 1<br>3. SOURCE 2<br>4. GATE 2<br>5. DRAIN 2<br>6. MIRROR 2<br>7. DRAIN 1<br>8. MIRROR 1   | <b>STYLE 20:</b><br>PIN 1. SOURCE (N)<br>2. GATE (N)<br>3. SOURCE (P)<br>4. GATE (P)<br>5. DRAIN<br>6. DRAIN<br>7. DRAIN<br>8. DRAIN   |
| <b>STYLE 21:</b><br>PIN 1. CATHODE 1<br>2. CATHODE 2<br>3. CATHODE 3<br>4. CATHODE 4<br>5. CATHODE 5<br>6. COMMON ANODE<br>7. COMMON ANODE<br>8. CATHODE 6  | <b>STYLE 22:</b><br>PIN 1. I/O LINE 1<br>2. COMMON CATHODE/VCC<br>3. COMMON CATHODE/VCC<br>4. I/O LINE 3<br>5. COMMON ANODE/GND<br>6. I/O LINE 4<br>7. I/O LINE 5<br>8. COMMON ANODE/GND | <b>STYLE 23:</b><br>PIN 1. LINE 1 IN<br>2. COMMON ANODE/GND<br>3. COMMON ANODE/GND<br>4. LINE 2 IN<br>5. LINE 2 OUT<br>6. COMMON ANODE/GND<br>7. COMMON ANODE/GND<br>8. LINE 1 OUT | <b>STYLE 24:</b><br>PIN 1. BASE<br>2. EMITTER<br>3. COLLECTOR/ANODE<br>4. COLLECTOR/ANODE<br>5. CATHODE<br>6. CATHODE<br>7. COLLECTOR/ANODE<br>8. COLLECTOR/ANODE                                      |
| <b>STYLE 25:</b><br>PIN 1. VIN<br>2. N/C<br>3. REXT<br>4. GND<br>5. IOUT<br>6. IOUT<br>7. IOUT<br>8. IOUT   | <b>STYLE 26:</b><br>PIN 1. GND<br>2. dv/dt<br>3. ENABLE<br>4. ILIMIT<br>5. SOURCE<br>6. SOURCE<br>7. SOURCE<br>8. VCC  | <b>STYLE 27:</b><br>PIN 1. ILIMIT<br>2. OVLO<br>3. UVLO<br>4. INPUT+<br>5. SOURCE<br>6. SOURCE<br>7. SOURCE<br>8. DRAIN  | <b>STYLE 28:</b><br>PIN 1. SW_TO_GND<br>2. DASIC_OFF<br>3. DASIC_SW_DET<br>4. GND<br>5. V_MON<br>6. VBULK<br>7. VBULK<br>8. VIN  |
| <b>STYLE 29:</b><br>PIN 1. BASE, DIE #1<br>2. EMITTER, #1<br>3. BASE, #2<br>4. EMITTER, #2<br>5. COLLECTOR, #2<br>6. COLLECTOR, #2<br>7. COLLECTOR, #1<br>8. COLLECTOR, #1                        | <b>STYLE 30:</b><br>PIN 1. DRAIN 1<br>2. DRAIN 1<br>3. GATE 2<br>4. SOURCE 2<br>5. SOURCE 1/DRAIN 2<br>6. SOURCE 1/DRAIN 2<br>7. SOURCE 1/DRAIN 2<br>8. GATE 1                           |  |  |

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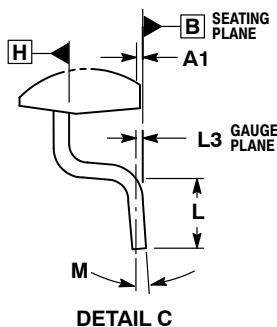
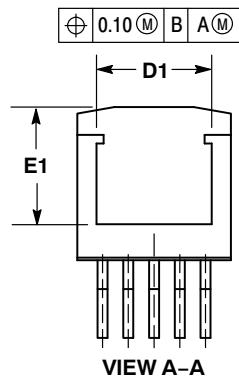
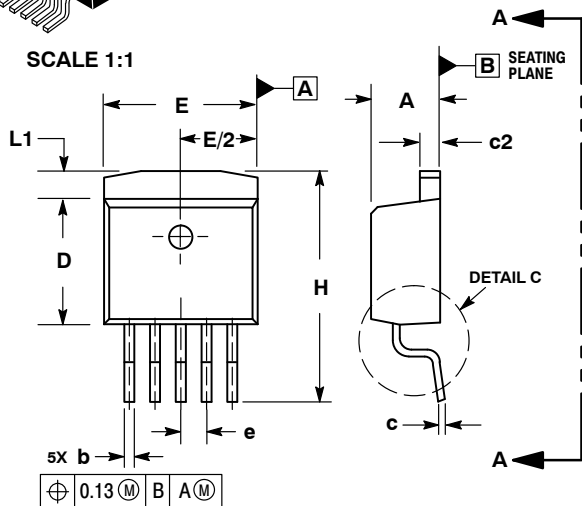
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D<sup>2</sup>PAK-5  
CASE 936AC  
ISSUE A

DATE 10 SEP 2009

SCALE 1:1

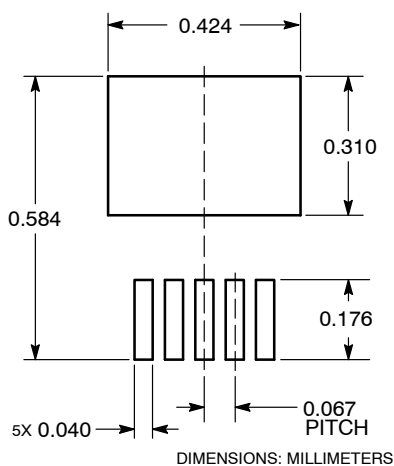


NOTES:

1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: INCHES.
3. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH AND GATE PROTRUSIONS. MOLD FLASH AND GATE PROTRUSIONS NOT TO EXCEED 0.005 MAXIMUM PER SIDE. THESE DIMENSIONS TO BE MEASURED AT DATUM H.
4. THERMAL PAD CONTOUR OPTIONAL WITHIN DIMENSIONS E, L1, D1, AND E1. DIMENSIONS D1 AND E1 ESTABLISH A MINIMUM MOUNTING SURFACE FOR THE THERMAL PAD.

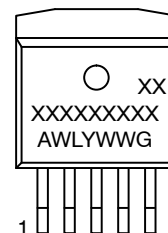
| DIM | INCHES    |       | MILLIMETERS |       |
|-----|-----------|-------|-------------|-------|
|     | MIN       | MAX   | MIN         | MAX   |
| A   | 0.170     | 0.180 | 4.32        | 4.57  |
| A1  | 0.000     | 0.010 | 0.00        | 0.25  |
| b   | 0.026     | 0.036 | 0.66        | 0.91  |
| c   | 0.017     | 0.026 | 0.43        | 0.66  |
| c2  | 0.045     | 0.055 | 1.14        | 1.40  |
| D   | 0.325     | 0.368 | 8.25        | 9.53  |
| D1  | 0.250     | ---   | 6.35        | ---   |
| E   | 0.380     | 0.420 | 9.65        | 10.67 |
| E1  | 0.200     | ---   | 5.08        | ---   |
| e   | 0.067 BSC |       | 1.70 BSC    |       |
| H   | 0.580     | 0.620 | 14.73       | 15.75 |
| L   | 0.090     | 0.110 | 2.29        | 2.79  |
| L1  | ---       | 0.066 | ---         | 1.68  |
| L3  | 0.010 BSC |       | 0.25 BSC    |       |
| M   | 0 °       | 8 °   | 0 °         | 8 °   |

RECOMMENDED  
SOLDERING FOOTPRINT\*



\*For additional information on our Pb-Free strategy and soldering details, please download the **onsemi** Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

GENERIC  
MARKING DIAGRAM\*



XXXXX = Specific Device Code  
A = Assembly Location  
WL = Wafer Lot  
Y = Year  
WW = Work Week  
G = Pb-Free Package

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "▪", may or may not be present.

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